

DP-305613

METHOD OF MOUNTING A LEADLESS
PACKAGE AND STRUCTURE THEREFOR

CROSS REFERENCE TO RELATED APPLICATIONS

[0001] Not applicable.

STATEMENT REGARDING FEDERALLY SPONSORED RESEARCH

[0002] Not applicable.

BACKGROUND OF THE INVENTION

(1) FIELD OF THE INVENTION

[0003] The present invention generally relates to semiconductor integrated circuit (IC) devices. More particularly, this invention relates to a method and structure for solder-mounting a leadless IC package to a substrate equipped with thermal vias, and for preventing solder from entering the vias during solder reflow.

(2) DESCRIPTION OF THE RELATED ART

[0004] Various packaging configurations have been proposed for mounting IC devices to circuit boards and other electronic substrates. Conventional packages typically require wire leads that electrically connect the package to contact pads on the surface of the circuit board. Leadless packages have been developed that do not have wire leads, but instead have input/output (I/O) pads exposed at a surface of the package. Such packages are known in the industry as quad flat non-leaded (QFN) packages. An example is a QFN

package commercially available from Amkor Technology under the name Microleadframe (MLF). As represented in Figure 1, the Amkor MLF package is a plastic-encapsulated IC package 30 with a copper leadframe 46 that defines lands (I/O pads) 40 near the outer perimeter of the package 30. An IC device 42 is attached to a die paddle (thermal pad) 32 located on the same surface of the package 30 as the pads 40 and surrounded by the pads 40. Wire leads 44 electrically connect the IC device 42 to the I/O pads 40, which in turn are electrically and mechanically connected with solder joints to contact pads on a circuit board or other suitable substrate. The thermal pad 32 promotes heat transfer from the IC device 42 to the circuit board. The circuit board can be equipped with a thermal pad on its surface for contact with the thermal pad 32 of the package 30 to promote heat transfer and dissipation in the circuit board. Heat transfer is promoted by soldering the thermal pad 32 to the thermal pad of the circuit board, and further by forming plated vias (plated through-holes, or PTH's) in the thermal pad of the circuit board to promote heat transfer through the circuit board to the surface opposite the package 30, where a heat sink or other suitable means can be provided for dissipating heat.

[0005] The solder joints at the I/O pads of a leadless package must be sufficiently thick (in the direction normal to the pads) to be compliant for surviving numerous thermal cycles. Solder joint height at the pads is affected by the relatively large volume of solder present between the thermal pads of the package and circuit board. If thermal vias are present in the thermal pad of the circuit board, loss of solder through the vias during reflow can cause the package to collapse toward the circuit board, reducing solder joint height. Figures 2 through 4 show a solution proposed in the past to prevent solder wicking into thermal vias. Figure 2 represents the surface of a substrate 112 prepared for mounting a leadless package, e.g., the package 30 of Figure 1. The substrate 112 is shown as having a thermal pad 114 surrounded by input/output pads 116, and with plated thermal vias 118 in the thermal pad

114 and extending through the substrate 112. A solder mask is shown as having been applied to the surface of the substrate 112, with openings 124 and 126 patterned in the solder mask to define an outer mask portion 120 surrounding the thermal pad 114 and interior mask portions 122 covering each of the vias 118, thereby plugging or "tenting" the vias 118. As represented in Figure 3, solder paste 134 is then applied to the thermal pad 114, and the leadless package 30 is placed on the substrate 112 so that its thermal pad 32 is registered with the solder paste 134. Solder paste is also deposited on the contact pads 116 (shown in Figure 2) at the same time as the paste 134 is deposited on the thermal pad 114, such that the I/O pads 40 of the package 30 also register with solder paste. The solder paste 134 is then reflowed to form a solder joint 136 between the thermal pads 114 and 32, as depicted in Figure 4, as well as solder joints that electrically connect the I/O pads 40 to the contact pads 116.

[0006] Figures 3 and 4 show the vias 118 as also being closed by solder masks 128 applied to the lower surface of the substrate 112. In practice, only one of the sets of solder masks 122 or 128 would typically be used to plug the vias 118. Reported experiments suggest that masking the vias 118 at the surface of the thermal pad 114 (with solder masks 122) provides better results in terms of reducing void formation during reflow.

BRIEF SUMMARY OF THE INVENTION

[0007] The present invention is directed to a method and circuit structure for mounting a leadless IC device to a substrate, such as a circuit board. The method and structure are directed to mounting a leadless device to a substrate having a thermal pad on a first surface thereof, a plurality of contact pads surrounding the thermal pad, and one or more plated vias in the thermal pad and extending through the substrate to an oppositely-disposed second surface of the substrate. The leadless device comprises a thermal pad

disposed at a surface of the leadless device for alignment with the substrate thermal pad, a plurality of input/output pads surrounding the device thermal pad for alignment with the contact pads of the substrate, and an integrated circuit device electrically connected to the input/output pads. The leadless device is attached to the substrate with solder that thermally connects the device thermal pad to the substrate thermal pad. To prevent solder flow into the plated vias during reflow, solder mask is provided on the first surface of the substrate, at least a portion of which is deposited on the substrate thermal pad and surrounds the plated via but does not block the plated via. In this manner, the portion of the solder mask defines a barrier between the solder and the plated via, but allows for outgassing through the via during the reflow process.

[0008] In view of the above, the present invention provides a solution to the problem of solder wicking through thermal vias during reflow, without resorting to blocking the vias as was believed necessary in the past. As a result, solder joints having adequate thicknesses can be readily achieved, promoting the reliability of the leadless device. An added benefit is the reduction in voids within the solder joint between the thermal pads of the leadless device and substrate as a result of the vias enabling flux outgassing during solder reflow. The solder mask remains as a permanent structure between the leadless device and the substrate, and can be selectively applied to closely surround the perimeters of the individual vias so that the remaining surface of the substrate thermal pad is exposed for attachment with solder to the leadless device. The solder mask can also be patterned to define a grid through which limited surface regions of the substrate thermal pad are exposed, creating multiple solder joints defined between the thermal pads of the leadless device and substrate.

[0009] Other objects and advantages of this invention will be better appreciated from the following detailed description.

BRIEF DESCRIPTION OF THE DRAWINGS

[0010] Figure 1 is a cross-sectional view of a leadless IC package.

[0011] Figure 2 is a plan view of a substrate equipped with a thermal pad and plated vias for mounting a leadless package in accordance with the prior art.

[0012] Figures 3 and 4 illustrate processing steps for mounting a leadless package to the substrate of Figure 1.

[0013] Figure 5 is a plan view of a substrate equipped with a thermal pad, plated vias and solder mask for mounting a leadless package in accordance with a preferred embodiment of the present invention.

[0014] Figures 6 through 8 illustrate processing steps for mounting a leadless package to the substrate of Figure 5.

DETAILED DESCRIPTION OF THE INVENTION

[0015] Figure 5 represents a circuit structure 10 in accordance with a preferred embodiment of this invention. Figure 5 shows a surface of a substrate 12 prepared for mounting a leadless package, represented as the MLF package 30 of Figure 1, and is therefore similar in appearance to the substrate surface depicted in Figure 2. However, the substrate 12 could be configured for mounting other types of leadless (QFN) packages. The substrate 12 may be a printed circuit board (PCB), flexible circuit, or a silicon, ceramic or insulated metal substrate, as is known in the art. In practice, an organic-based laminate PCB having a thickness of about 0.062 inch (about 1.57 mm) has been found to be suitable. A thermal pad 14 and surrounding I/O pads 16 are shown as having been formed on the surface of

the substrate 12. The thermal pad 14 and I/O pads 16 are preferably formed of copper, such as by etching copper that has been cladded, laminated, plated or otherwise deposited on the surface of the substrate 12, though the use of other conductive materials and deposition techniques are within the scope of this invention. Plated thermal vias 18 are shown as being defined in the substrate thermal pad 14 and extending through the substrate 12. While a 4x4 matrix of vias 18 is shown, any number of vias 18 could be used, depending on the size of the thermal pad 14 and package 30. Suitable methods for forming the vias 18 and depositing a thermally conductive material (e.g., copper) are well known in the art, and therefore will not be discussed here. The after-plated diameters of the vias 18 are preferably on the order of about 0.425 to about 0.575, nominally about 0.50 mm.

[0016] Figure 5 also shows a solder mask 20 that has been applied and patterned on the surface of the substrate 12. The mask 20 is preferably formed of a photoimageable material having acceptable feature definition and thickness properties for the process to be described below. A suitable photoimageable material for this purpose is a solder mask available from Vantico under the name Probimer 77MA, though other suitable solder mask materials could be used. In Figure 5, the mask 20 has been imaged and openings 24 and 26 have been developed in accordance with known practices for the particular mask material. The openings 24 are shown as exposing each set of pads 16, while the openings 26 expose multiple surface regions of the thermal pad 14. As evident from Figure 5, the openings 26 are patterned such that the solder mask 20 defines a grid over the thermal pad 14, with annular-shaped portions 21 of the mask 20 surrounding each of the vias 18 and with rectilinear portions 22 therebetween that interconnect the annular-shaped portions 21. From Figures 5 and 6, it can be seen that the annular-shaped portions 21 closely surround the vias 18, preferably contacting the edge of each via 18 at the substrate surface and slightly intruding into the vias 18. However, the annular-shaped portions 21 do not block the vias 18.

[0017] The exposed pads 16 and the multiple surface regions of the thermal pad 14 delineated by the rectilinear portions 22 of the mask 20 provide locations for receiving solder that will bond the leadless package 30 to the substrate 12, as shown in Figures 6 and 7. Figure 6 depicts the deposition of a solder paste 34 through a stencil 38 positioned and aligned on the surface of the substrate 12 so that the paste 34 is selectively deposited on the pads 16 (not shown) and the exposed surface regions of the substrate thermal pad 14. The paste 34 is a mixture of a flux compound and particles of a suitable solder alloy, such as 60Sn-40Pb or 63Sn-37Pb. From Figure 6, it is evident that the solder paste 34 on the thermal pad 14 between adjacent vias 18 has been deposited to a thickness significantly greater than the thickness of the annular-shaped portions 21 of the solder mask 20. Consequently, the solder mask 20 is not required to establish or limit the amount of solder (36 in Figure 8) that will bond the package 30 to the substrate 12, and the solder paste 34 deposited with the stencil 38 can and preferably does exceed the thickness of the solder mask 20. For example, using a solder mask 20 (including the portions 21 and 22) having a thickness of about 10 to about 25 micrometers, the stencil 38 can be used to deposit solder paste 34 to a thickness of about 0.005 to about 0.006 inch (about 125 to about 150 micrometers). In this manner, sufficient solder paste 34 can be deposited to form solder joints 36 of adequate thickness to be reliable when subjected to thermal excursions. A suitable thickness for the solder joints 36 is believed to be in excess of twenty-five micrometers, though greater and lesser thicknesses may be appropriate, depending on the geometries and materials of the components.

[0018] In Figure 7, the stencil 38 has been removed and the leadless package 30 registered with the substrate 12 so that a thermal pad 32 on the surface of the package 30 contacts the solder paste 34 deposited on the substrate thermal pad 14, i.e., between the vias 18. Simultaneously, I/O pads (not shown) located near the perimeter of the package 30 and surrounding the package thermal pad 32 are registered with the contact pads 16 on the

substrate 12. Thereafter, the resulting assembly 10 is heated sufficiently to vaporize or burn off the flux and melt the solder alloy particles of the solder paste 36, yielding the solder joints 36 depicted in Figure 8 as physically and thermally connecting the thermal pad 32 of the package 30 to the thermal pad 14 of the substrate 12. As evident from Figure 8, the annular-shaped portions 21 of the solder mask 20 provide barriers surrounding the vias 18 that prevent the molten solder from wicking into and potentially blocking the vias 18. It is believed that the annular-shaped portions 21 are effective as barriers at thicknesses of as little as about 10 micrometers and widths (the difference between the radii of the portion 21 and via 18) of as little as about 150 micrometers.

[0019] Because the portions 21 prevent the molten solder 36 from entering the vias 18, the solder 36 remains between the package 30 and substrate 12 and prevents the package 30 from being drawn excessively close to the substrate 12 during reflow, which could reduce the height of the solder joints 36 to the point where reliability of the solder joint 36 is reduced. In addition, during the reflow process, gases that evolve from the flux are able to escape through the vias 18, thereby reducing the likelihood of voids being created in the solder joints 36. The absence or reduction in voids further promotes the reliability of the solder joints 36 and heat transfer from the package 30 to the substrate 12.

[0020] When placed in service, heat generated by the package 30 is readily conducted to the lower surface of the substrate 12 through the thermal pads 14 and 32 and the metal walls of the vias 18, thereby dissipating heat away from the package 30. The substrate 12 can be subsequently mounted to a heat sink (not shown) to promote thermal dissipation. Figures 6 through 8 depict annular-shaped solder mask portions 23 applied around the openings to the vias 18 at the surface of the substrate 12 opposite the thermal pad 14. These mask portions 23 are useful if solder is to be applied to the lower

surface of the substrate 12, such as a wave soldering process to attach stick-lead components to the upper surface of the substrate 12.

[0021] While the invention has been described in terms of a preferred embodiment, it is apparent that other forms could be adopted by one skilled in the art. For example, the substrate 12, vias 18 and package 30 could be configured differently from those shown in the Figures and yet achieve the objects of this invention, and different materials could be used than those noted. Accordingly, the scope of the invention is to be limited only by the following claims.

CLAIMS

1. A circuit structure comprising:

a substrate having a substrate thermal pad on a first surface thereof, a plurality of contact pads on the first surface and surrounding the substrate thermal pad, and at least one plated via in the substrate thermal pad and extending through the substrate to an oppositely-disposed second surface of the substrate;

solder mask on the first surface of the substrate, at least a portion of the solder mask being on the substrate thermal pad and surrounding the plated via but not blocking the plated via;

a leadless package on the first surface of the substrate, the leadless package comprising a package thermal pad disposed at a surface of the leadless package and aligned with the substrate thermal pad of the substrate, a plurality of input/output pads surrounding the package thermal pad and aligned with the contact pads of the substrate, and an integrated circuit device electrically connected to the input/output pads; and

solder thermally connecting the package thermal pad to the substrate thermal pad, the portion of the solder mask defining a barrier between the solder and the plated via.

2. The circuit structure according to claim 1, further comprising a second solder mask on the second surface of the substrate, at least a portion of the second solder mask surrounding the plated via but not blocking the plated via.

3. The circuit structure according to claim 1, further comprising a second solder electrically connecting the input/output pads of the leadless package to the contact pads of the substrate.

4. The circuit structure according to claim 3, wherein the

second solder has a thickness of greater than 25 micrometers in a direction normal to the input/output pads and the contact pads.

5. The circuit structure according to claim 1, wherein the portion of the solder mask has an annular shape.

6. The circuit structure according to claim 1, wherein the portion of the solder mask contacts an edge of the plated via at the first surface of the substrate.

7. A circuit structure comprising:

a substrate having a metal substrate thermal pad on a first surface thereof, a plurality of metal contact pads on the first surface and surrounding the substrate thermal pad, and a plurality of metal-plated vias in the substrate thermal pad and extending through the substrate to an oppositely-disposed second surface of the substrate;

solder mask comprising first portions on the substrate thermal pad, surrounding each of the plated vias but not blocking the plated vias, and exposing surface regions of the substrate thermal pad between the plated vias;

a leadless package on the first surface of the substrate, the leadless package comprising a metal package thermal pad disposed at a surface of the leadless package and aligned with the substrate thermal pad, a plurality of metal input/output pads surrounding the package thermal pad and aligned with the contact pads of the substrate, and an integrated circuit device electrically connected to the input/output pads;

first solder thermally connecting the package thermal pad to the surface regions of the substrate thermal pad exposed by the first portions of the solder mask, the first portions of the solder mask defining barriers between the first solder and the plated vias; and

second solder electrically connecting the input/output pads of the leadless package to the contact pads of the substrate.

8. The circuit structure according to claim 7, further comprising a second solder mask on the second surface of the substrate, at least portions of the second solder mask surrounding each of the plated vias but not blocking the plated via.

9. The circuit structure according to claim 7, wherein the second solder has a thickness of greater than 25 micrometers in a direction normal to the input/output pads and the contact pads.

10. The circuit structure according to claim 7, wherein each of the first portions of the solder mask surrounding the plated vias has an annular shape.

11. The circuit structure according to claim 7, wherein each of the first portions of the solder mask surrounding the plated vias contacts an edge of a corresponding one of the plated vias at the first surface of the substrate.

12. The circuit structure according to claim 7, wherein the solder mask comprises second portions on the substrate thermal pad, the second portions being configured as a grid that interconnects the first portions of the solder mask and defines regions between the plated vias in which the first solder is located.

13. A method of attaching a leadless package to a substrate having a substrate thermal pad on a first surface thereof, a plurality of contact pads on the first surface and surrounding the substrate thermal pad, and at least one plated via in the substrate thermal pad and extending through the substrate to an oppositely-disposed second surface of the substrate, the method comprising the steps of:

depositing a solder mask on the first surface of the substrate so that at least a first portion of the solder mask is on the substrate thermal pad and surrounds the plated via but does not block the plated via;

depositing solder on the contact pads and on regions of the substrate thermal pad exposed by the first portion of the solder mask;

placing a leadless package on the first surface of the substrate, the leadless package comprising a package thermal pad disposed at a surface of the leadless package, a plurality of input/output pads surrounding the package thermal pad, and an integrated circuit device electrically connected to the input/output pads, the leadless package being placed on the substrate so that the input/output pads contact the solder on the contact pads of the substrate and so that the package thermal pad contacts the solder deposited on the regions of the substrate thermal pad exposed by the first portion of the solder mask; and

reflowing the solder to form solder joints that thermally connect the package thermal pad to the substrate thermal pad and electrically connect the input/output pads of the leadless package to the contact pads of the substrate, the first portion of the solder mask preventing the solder from flowing into the plated via during the reflow step and thereby promoting the thickness of the solder joints.

14. The method according to claim 13, further comprising the step of depositing a second solder mask on the second surface of the substrate, at least a portion of the second solder mask surrounding the plated via but not blocking the plated via.

15. The method according to claim 13, wherein gases evolve during the reflow step and escape from between the leadless package and the substrate through the plated via.

16. The method according to claim 13, wherein the solder joints on the contact pads have thicknesses of greater than 25 micrometers in a direction normal to the input/output pads and the contact pads following the reflow step.

17. The method according to claim 13, wherein the solder mask is deposited so that the first portion of the solder mask has an annular shape.

18. The method according to claim 13, wherein the solder mask is deposited so that the first portion of the solder mask contacts an edge of a corresponding one of the plated vias at the first surface of the substrate.

19. The method according to claim 13, wherein a plurality of the plated vias are present in the substrate thermal pad and extend through the substrate to the second surface of the substrate, and the solder mask is deposited so that each of the plated vias is surrounded by the first portion of the solder mask and the first portion of the solder mask contacts an edge of each of the plated vias at the first surface of the substrate.

20. The method according to claim 19, wherein the solder mask comprises a second portion on the substrate thermal pad, the second portion being configured as a grid interconnected with the first portion of the solder mask and defining regions between the plated vias in which the solder is deposited.

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ABSTRACT OF THE INVENTION

A method and circuit structure for mounting a leadless IC package to a substrate having a thermal pad on a first surface thereof, a plurality of contact pads surrounding the thermal pad, and one or more plated vias in the thermal pad. The leadless package is attached to the substrate with solder that thermally connects the package to the thermal pad. To prevent solder flow into the plated vias during reflow, a solder mask is provided on the first surface of the substrate, at least a portion of which is deposited on the thermal pad and surrounds the plated vias but does not block the plated vias. The solder mask portion defines a barrier between the solder and the plated vias, but allows for outgassing through the vias during solder reflow.

CLAIMS

1. A circuit structure (10) comprising:

a substrate (12) having a substrate thermal pad (14) on a first surface thereof, a plurality of contact pads (16) on the first surface and surrounding the substrate thermal pad (14), and at least one plated via (18) in the substrate thermal pad (14) and extending through the substrate (12) to an oppositely-disposed second surface of the substrate (12);

solder mask (20,21,22) on the first surface of the substrate (12), at least a portion (21) of the solder mask (20,21,22) being on the substrate thermal pad (14) and surrounding the plated via (18) but not blocking the plated via (18);

a leadless package (30) on the first surface of the substrate (12), the leadless package (30) comprising a package thermal pad (32) disposed at a surface of the leadless package (30) and aligned with the substrate thermal pad (14) of the substrate (12), a plurality of input/output pads (40) surrounding the package thermal pad (32) and aligned with the contact pads (16) of the substrate (12), and an integrated circuit device (42) electrically connected to the input/output pads (40); and

solder (36) thermally connecting the package thermal pad (32) to the substrate thermal pad (14), the portion (21) of the solder mask (20,21,22) defining a barrier between the solder (36) and the plated via (18).

2. The circuit structure (10) according to claim 1, further comprising a second solder mask (23) on the second surface of the substrate (12), at least a portion of the second solder mask (23) surrounding the plated via (18) but not blocking the plated via (18).

3. The circuit structure (10) according to claim 1, further comprising a second solder (36) electrically connecting the input/output pads (40) of the leadless package (30) to the contact pads (16) of the substrate (12).

4. The circuit structure (10) according to claim 3, wherein the second solder (36) has a thickness of **greater** than 25 micrometers in a direction normal to the input/output pads (40) and the contact pads (16).

5. The circuit structure (10) according to claim 1, wherein the portion (21) of the solder mask (20,21,22) has an annular shape.

6. The circuit structure (10) according to claim 1, wherein the portion (21) of the solder mask (20,21,22) **contacts** an edge of the plated via (18) at the first surface of the substrate (12).

7. A method of attaching a leadless package (30) to a substrate (12) having a substrate thermal pad (14) **on** a first surface thereof, a plurality of contact pads (16) on the first surface **and** surrounding the substrate thermal pad (14), and at least one plated via (18) **in** the substrate thermal pad (14) and extending through the substrate (12) to **an** oppositely-disposed second surface of the substrate (12), the method comprising the steps of:

depositing a solder mask (20,21,22) on the first surface of the substrate (12) so that at least a first **portion** (21) of the solder mask (20,21,22) is on the substrate thermal pad (14) and **surrounds** the plated via (18) but does not block the plated via (18);

depositing solder (34) **on the** contact pads (16) and on regions of the substrate thermal pad (14) **exposed by** the first portion (21) of the solder mask (20,21,22);

placing a leadless package (30) on the first surface of the substrate (12), the leadless package (30) **comprising** a package thermal pad (32) disposed at a surface of the leadless **package** (30), a plurality of input/output pads (40) surrounding the **package** thermal pad (32), and an integrated circuit device (42) electrically **connected** to the input/output pads (40), the leadless package (30) being **placed** on the substrate (12) so that the input/output pads (40) contact the solder (34) on the contact pads (16) of the

substrate (12) and so that the package thermal pad (32) contacts the solder (34) deposited on the regions of the substrate thermal pad (14) exposed by the first portion (21) of the solder mask (20,21,22); and

reflowing the solder (34) to form solder joints (36) that thermally connect the package thermal pad (32) to the substrate thermal pad (14) and electrically connect the input/output pads (40) of the leadless package (30) to the contact pads (16) of the substrate (12), the first portion (21) of the solder mask (20,21,22) preventing the solder (34) from flowing into the plated via (18) during the reflow step and thereby promoting the thickness of the solder joints (36).

8. The method according to claim 7, further comprising the step of depositing a second solder mask (23) on the second surface of the substrate (12), at least a portion of the second solder mask (23) surrounding the plated via (18) but not blocking the plated via (18).

9. The method according to claim 7, wherein gases evolve during the reflow step and escape from between the leadless package (30) and the substrate (12) through the plated via (18).

10. The method according to claim 7, wherein the solder joints (36) on the contact pads (16) have thicknesses of greater than 25 micrometers in a direction normal to the input/output pads (40) and the contact pads (16) following the reflow step.

11. The method according to claim 7, wherein the solder mask (20,21,22) is deposited so that the first portion (21) of the solder mask (20,21,22) has an annular shape.

12. The method according to claim 7, wherein the solder mask (20,21,22) is deposited so that the first portion (21) of the solder mask

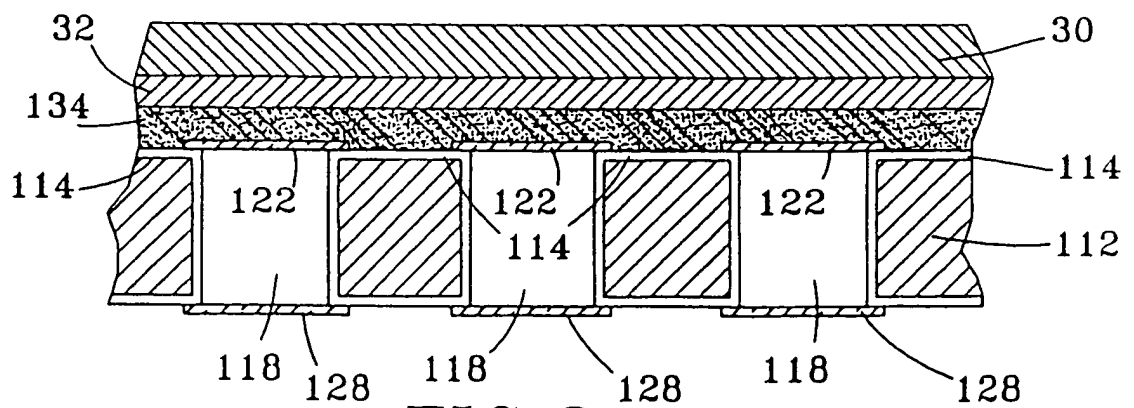
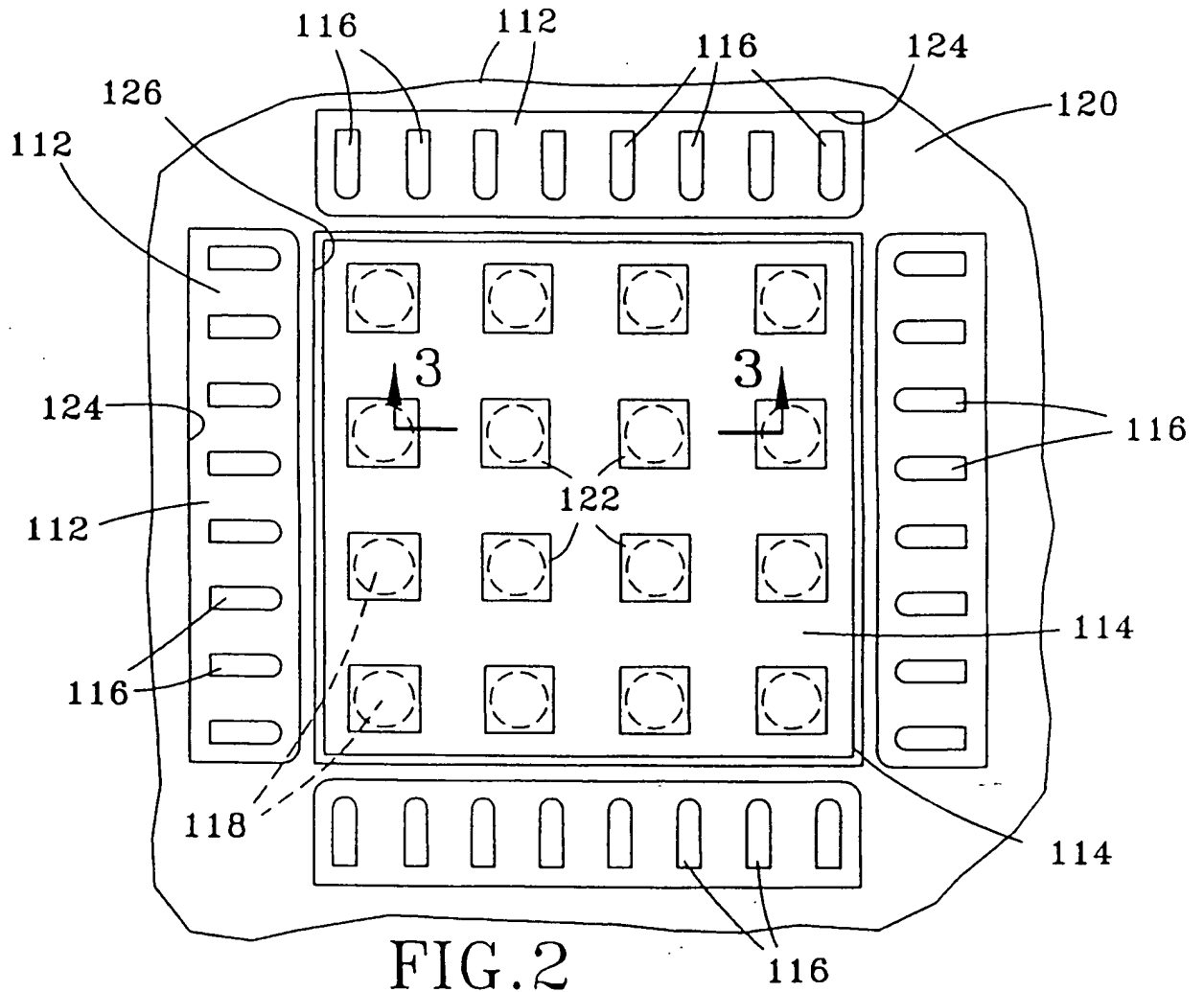
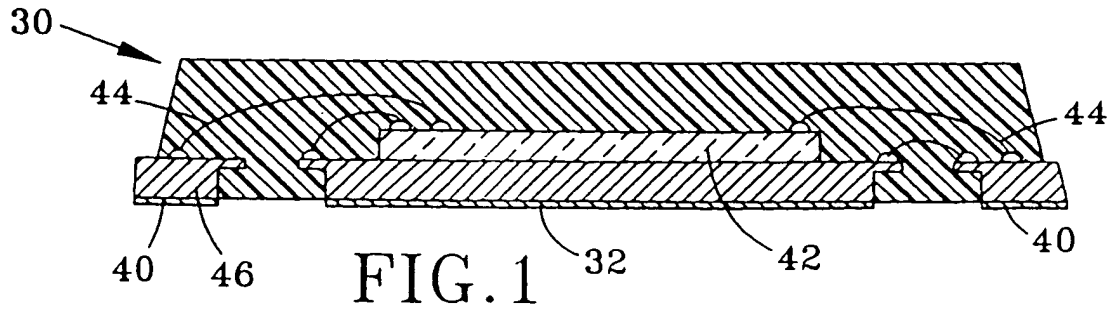
(20,21,22) contacts an edge of a corresponding one of the plated vias (18) at the first surface of the substrate (12).

13. The method according to claim 7, wherein a plurality of the plated vias (18) are present in the substrate thermal pad (14) and extend through the substrate (12) to the second surface of the substrate (12), and the solder mask (20,21,22) is deposited so that each of the plated vias (18) is surrounded by the first portion (21) of the solder mask (20,21,22) and the first portion (21) of the solder mask (20,21,22) contacts an edge of each of the plated vias (18) at the first surface of the substrate (12).

14. The method according to claim 13, wherein the solder mask (20,21,22) comprises a second portion (22) on the substrate thermal pad (14), the second portion (22) being configured as a grid interconnected with the first portion (21) of the solder mask (20,21,22) and defining regions between the plated vias (18) in which the solder (34) is deposited.

ABSTRACT OF THE INVENTION

A method and circuit structure (10) for mounting a leadless IC package (30) to a substrate (12) having a thermal pad (14) on a first surface thereof, a plurality of contact pads (16) surrounding the thermal pad (14), and one or more plated vias (18) in the thermal pad (14). The leadless package (30) is attached to the substrate (12) with solder (36) that thermally connects the package (30) to the thermal pad (14). To prevent solder flow into the plated vias (18) during reflow, a solder mask (20,21,22) is provided on the first surface of the substrate (12), at least a portion (21) of which is deposited on the thermal pad (14) and surrounds the plated vias (18) but does not block the plated vias (18). The solder mask portion (21) defines a barrier between the solder (36) and the plated vias (18), but allows for outgassing through the vias (18) during solder reflow.



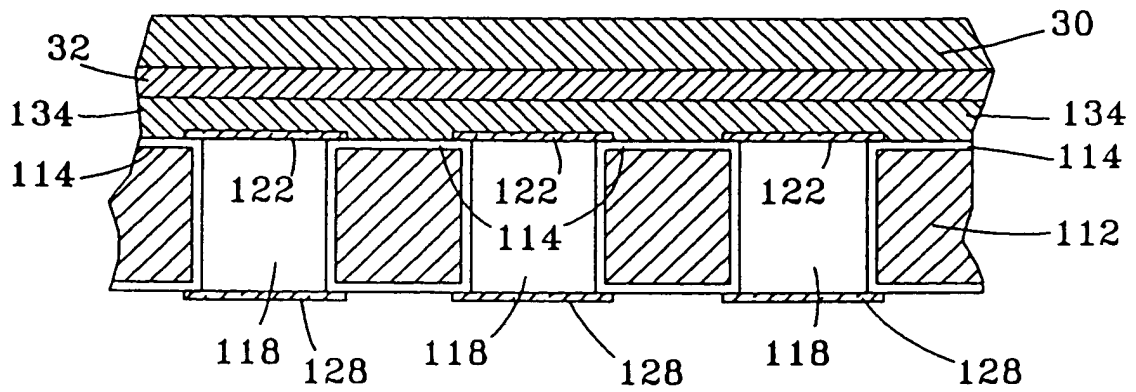


FIG. 4

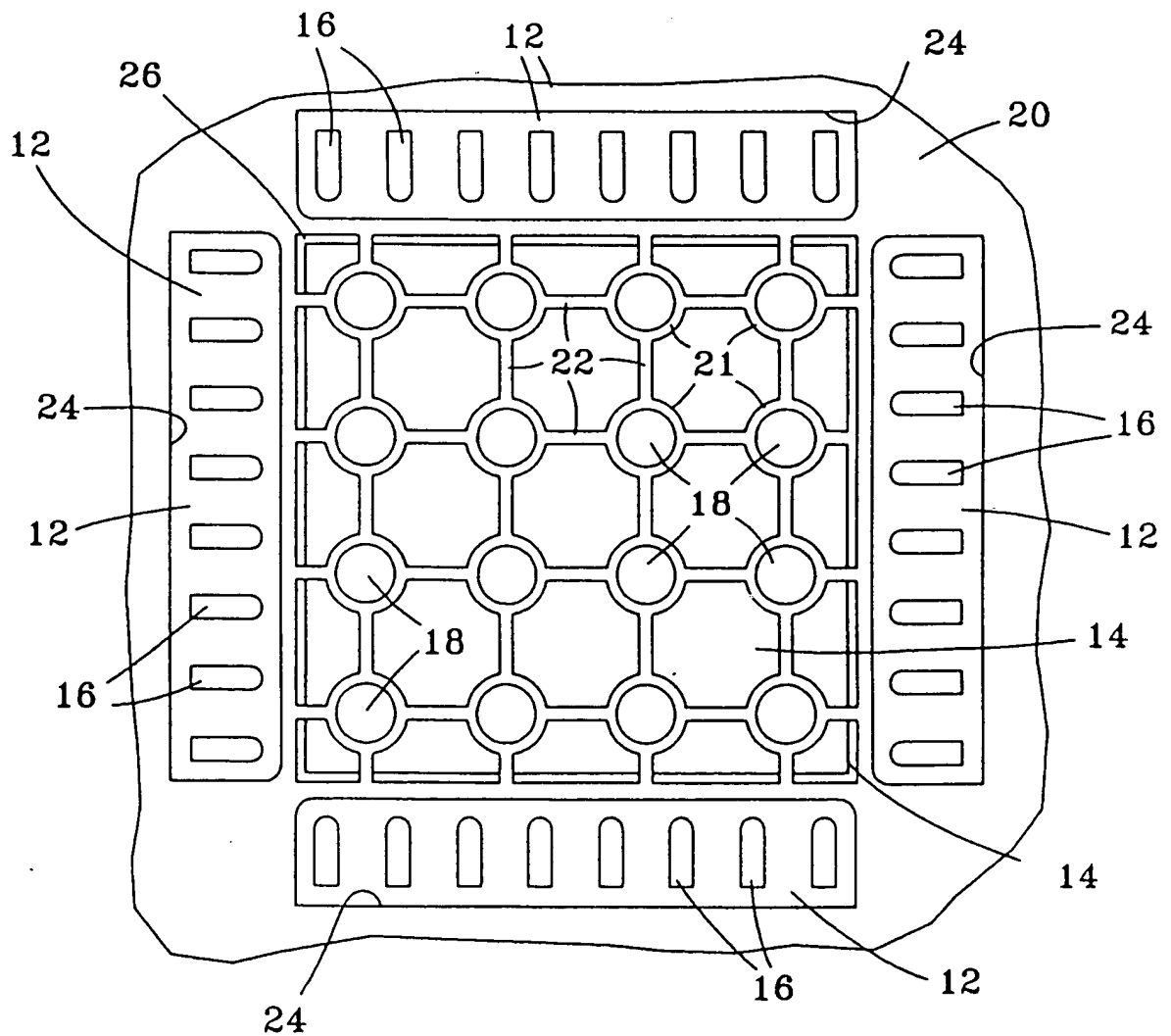


FIG. 5

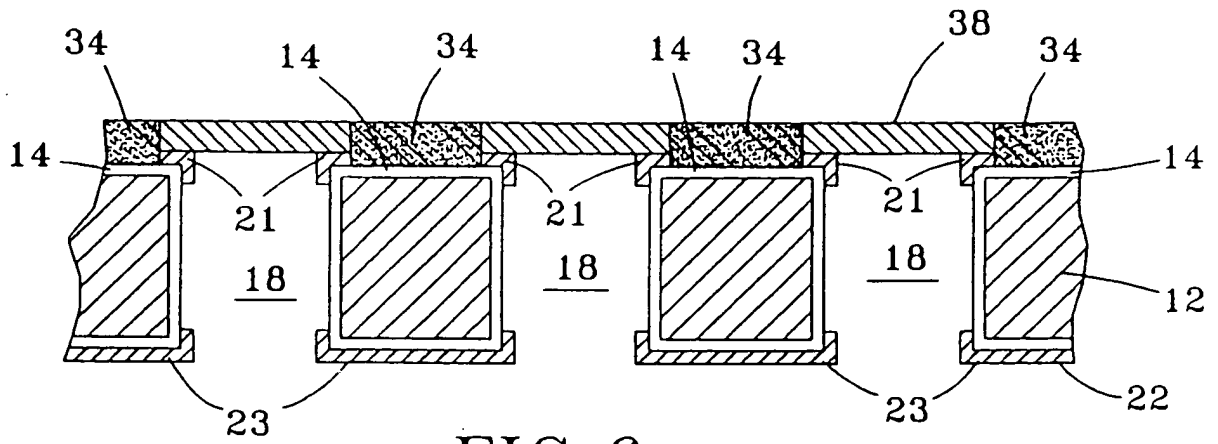


FIG. 6

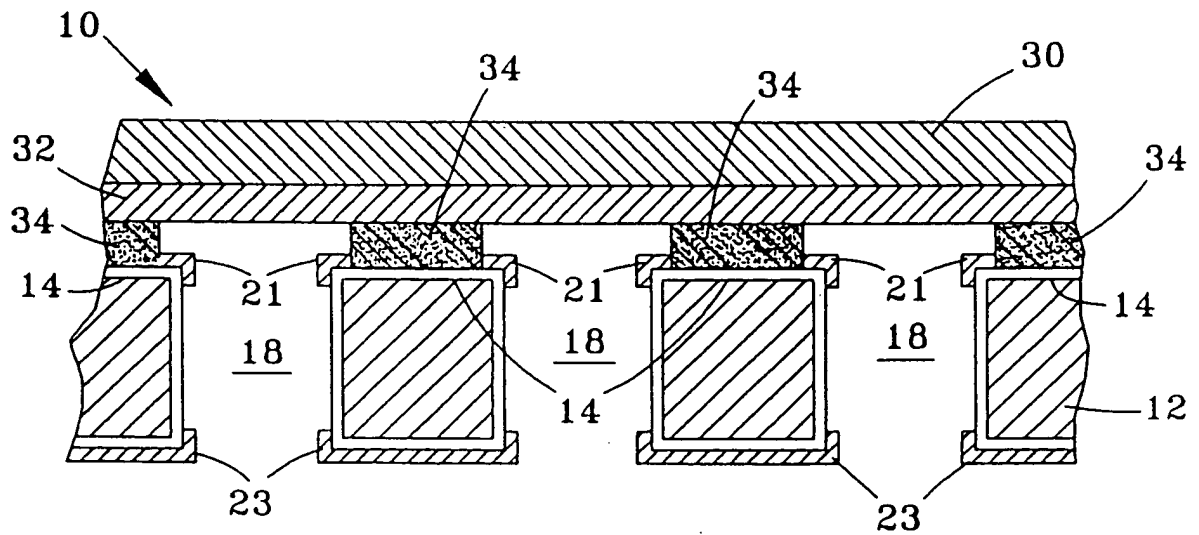


FIG. 7

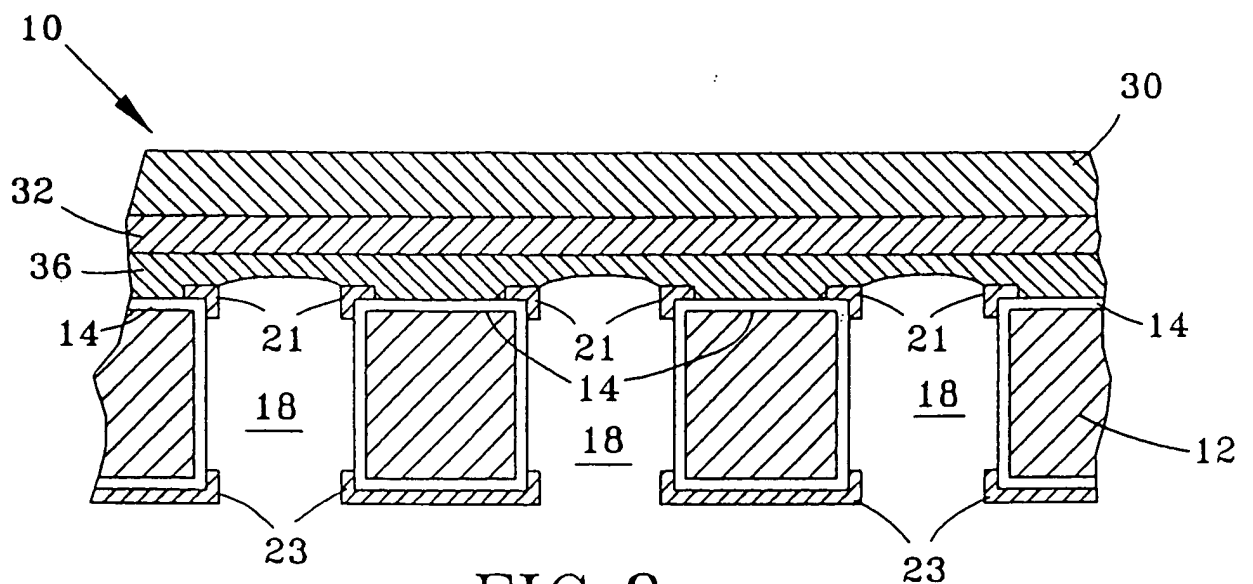


FIG. 8